

Resonac Photonics Corporation Marketing Department Email: RPC_Elled@resonac.com

Apr. 2023

KM91028NFMA-A

1. Material GaAlAs

2. Electrode N (cathode) side : Au

P (anode) side

3. Electrode pattern

4. Chip size $0.265 \text{ mm} \times 0.265 \text{ mm} \times 0.175 \text{ mm}$ (Fig.1)

5. Emission area 0.230mm X 0.230mm (Fig.1)

6. Electro-Optical characteristics (Ta = 25°C)

Parameters	Symbol	Condition	Min	Тур	Max	Unit
Power	Po	IF=20mA	2.0	4.3	-	mW
Forward Voltage	VF	IF=20mA	-	1.37	1.41	V
Reverse Current	IR	VR=3V	-	-	10	uA
Peak Wavelength	λр	IF=20mA	900	910	915	nm
Spectral Radiation	Δλ(*)	IF=20mA	-	45	-	nm
Bandwidth						

^{* (*)} mark is reference data

- * Power Measurement at Resonac Photonics.
- 7. Recommended bonding method Ultra-sonic method or a combination of ultra-sonic and thermo-compression methods.

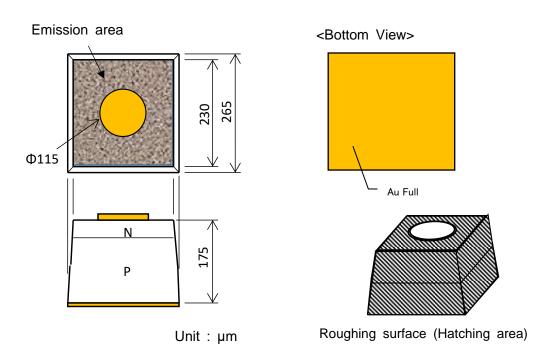


Fig.1: Chip size and Emission area and Electrode pattern

The information contained herein is believed to be reliable.

However, no representations, guaranties or warranties of any kind are made as to accuracy and suitability of the Product for particular applications or the results of its use.

Resonac Photonics Corporation reserves the right to introduce changes without notice.